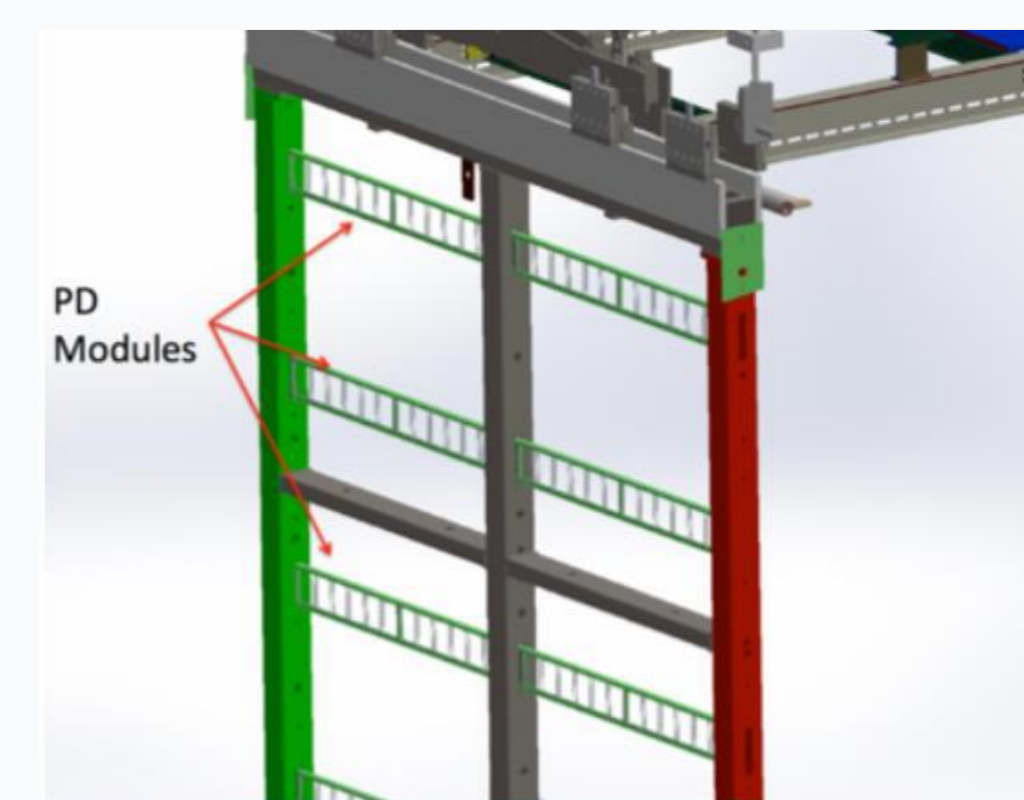
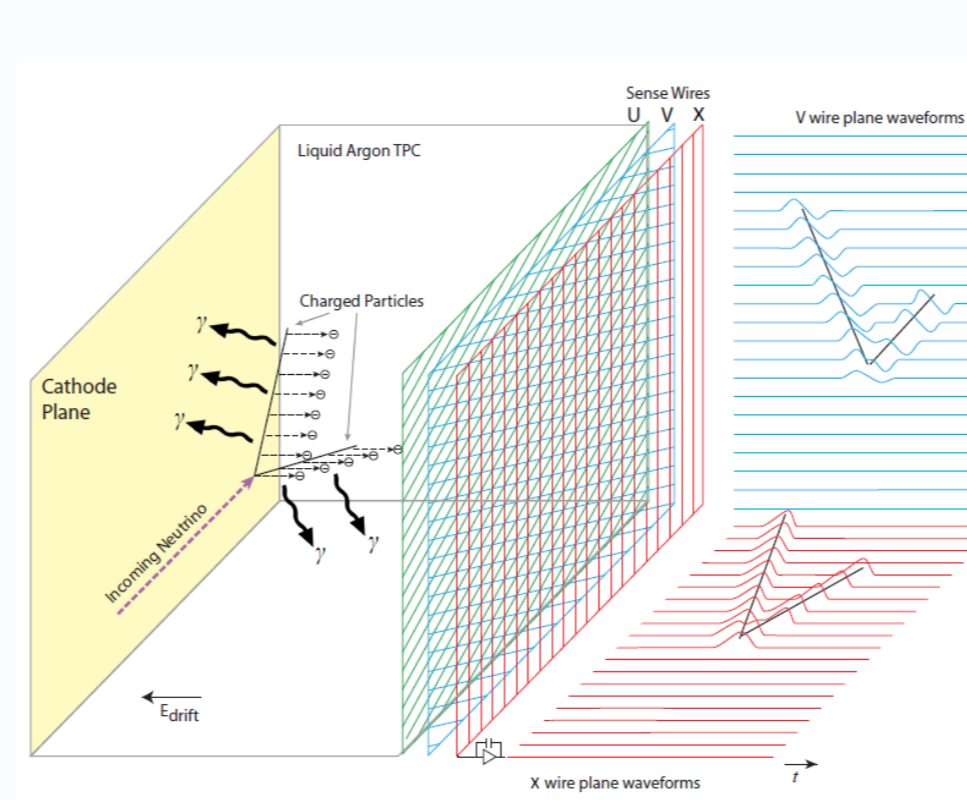
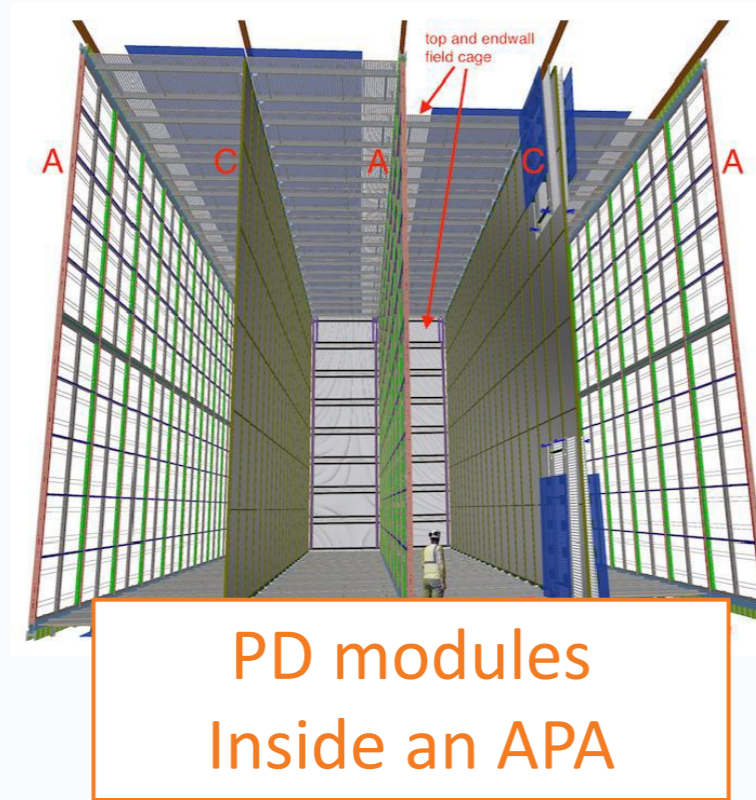


Single Phase DUNE Far Detector

- A 10 kilo tonne Single Phase LArTPC
- Read out the pattern of ionization with sub cm granularity
- Search from MeV to GeV scale neutrino interactions



Photon Detection System

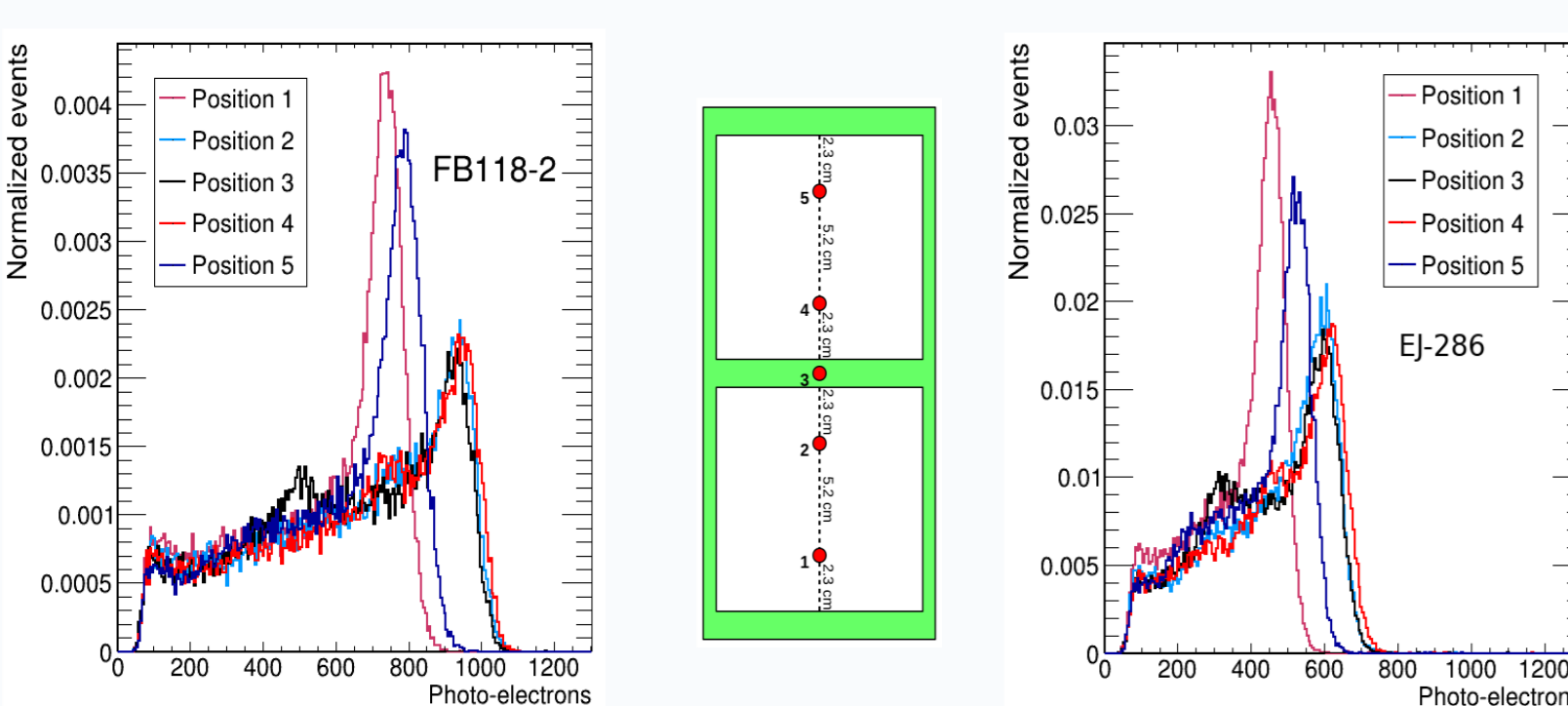
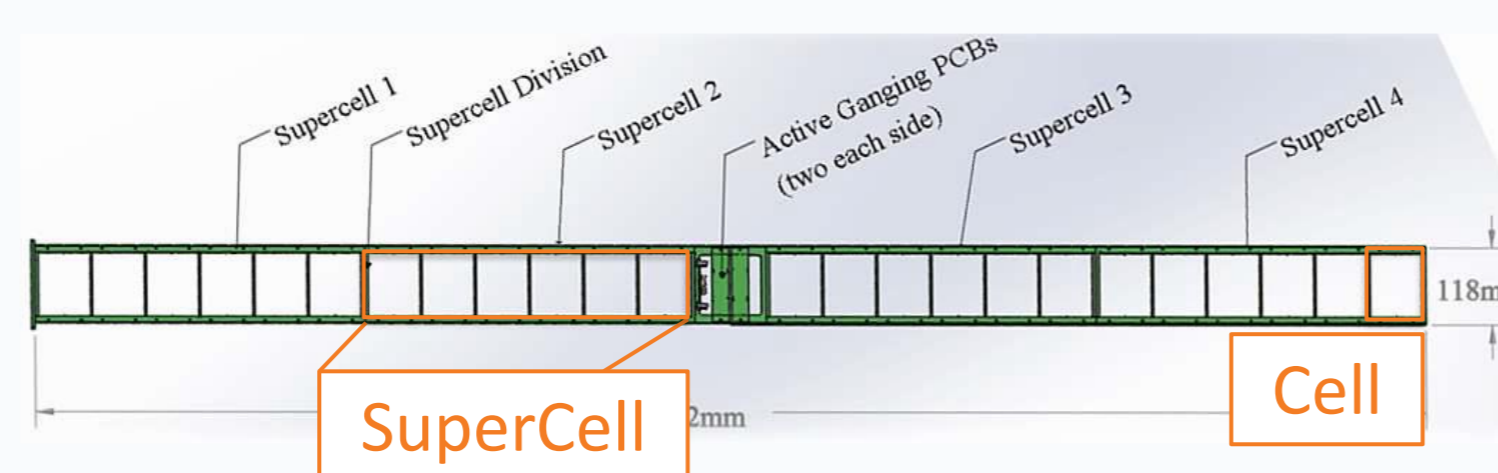
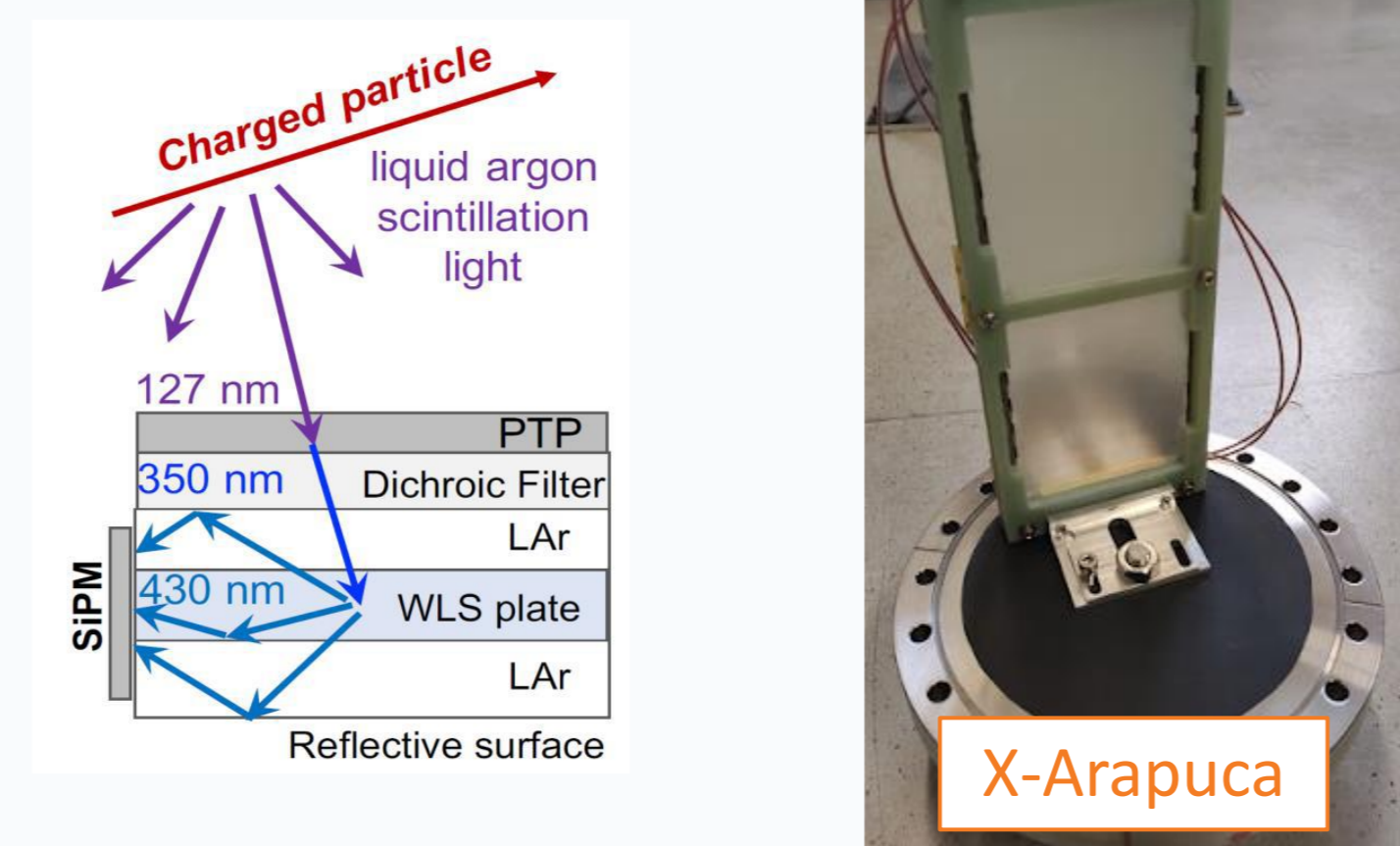
- Goals:
 - ✓ Maximize the active volume
 - ✓ Maximize the light yield
- Considerations:
 - ✓ Constraint of the APA structure
 - ✓ Cost effective: large area light collector minimizing photosensor coverage.

Light collectors: X-Arapuca

- The X-ARAPUCA design makes use of **total internal reflection** and highly reflective boxes to capture wavelength-shifted photons to improve detection efficiency.

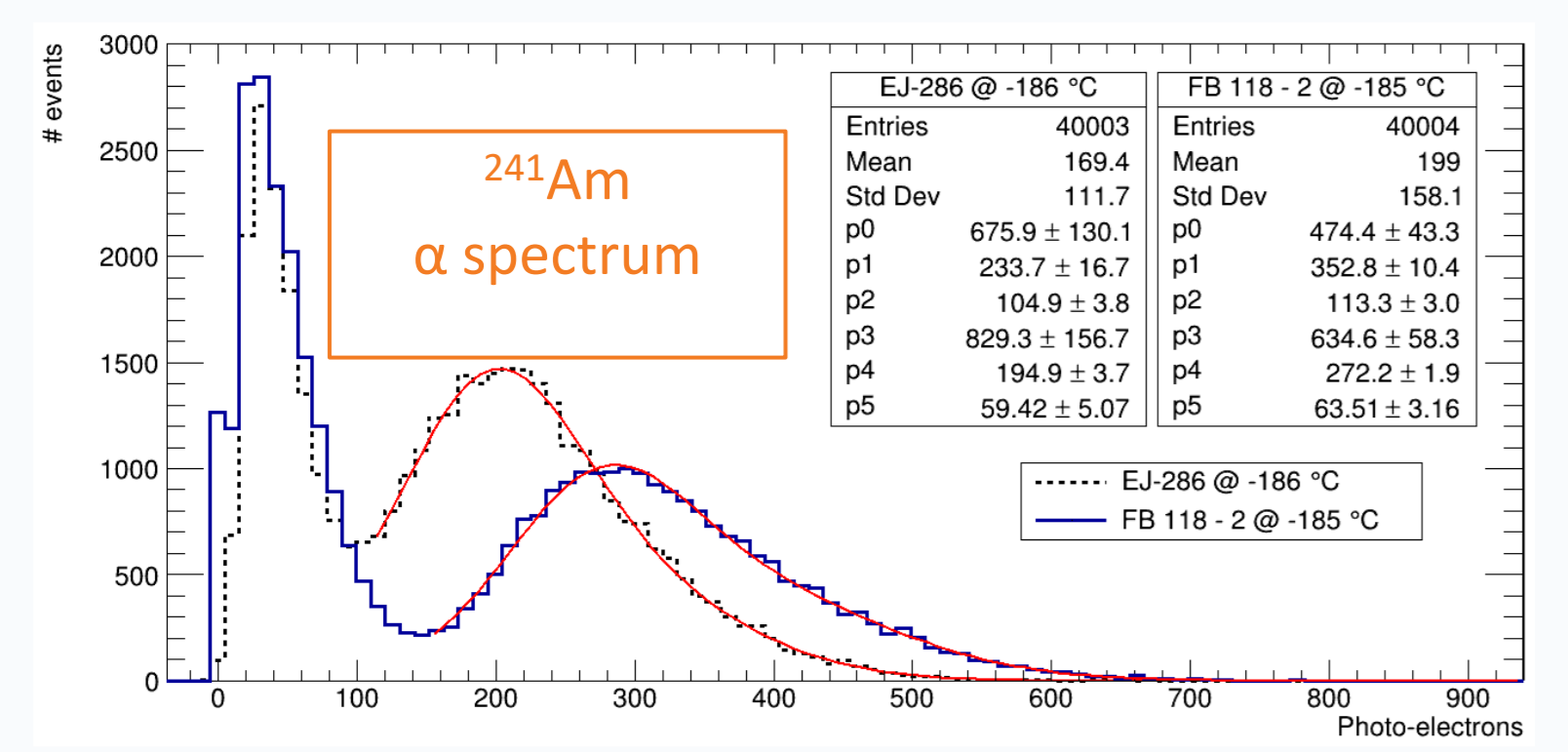
- Keys to an effective PD system in DUNE:
 - ✓ **Efficient conversion** of VUV photons to captured photons.
 - ✓ **High fraction** of captured photons incident on photosensors.
 - ✓ **Efficient photosensors** for converting photons into electric signals.

- **Supercell**: 6 cells 488 × 100 × 8 mm³.
- **PD Module**: 4 supercells 2092 × 118 × 23 mm³ (bars configuration).



- **Supercell test**: 2-window supercell tested.
- Test on **light collection uniformity and efficiency**.

- Test on **different WLS plates**:
 - ✓ Commercial (Eljen 286) WLS plate, with measured PDE of 2.8%.
 - ✓ **New WLS bars** (FB118-2, Acrylic matrix, higher efficiency) developed at MiB with PDE measured in same test stand 3.8%.

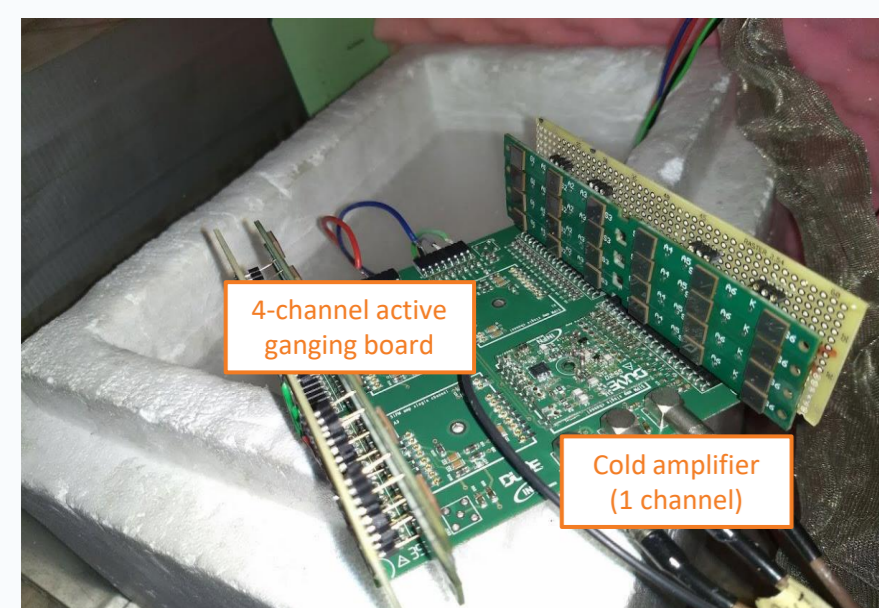


- **Supermodule test**
 - ✓ 2 supercells (half supermodule)
 - ✓ Allow to test all the electrical boards for DUNE

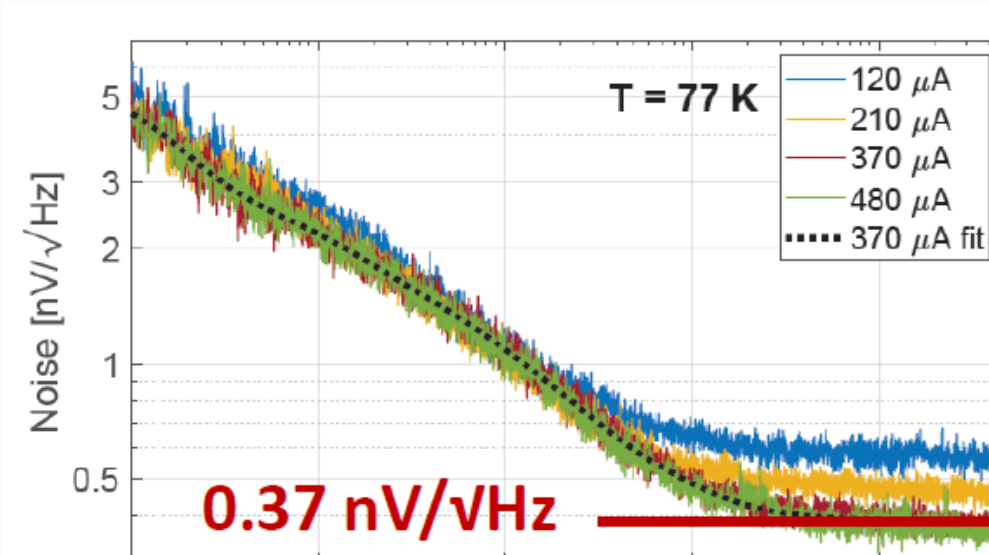
- Coating and assembly infrastructure are being completed



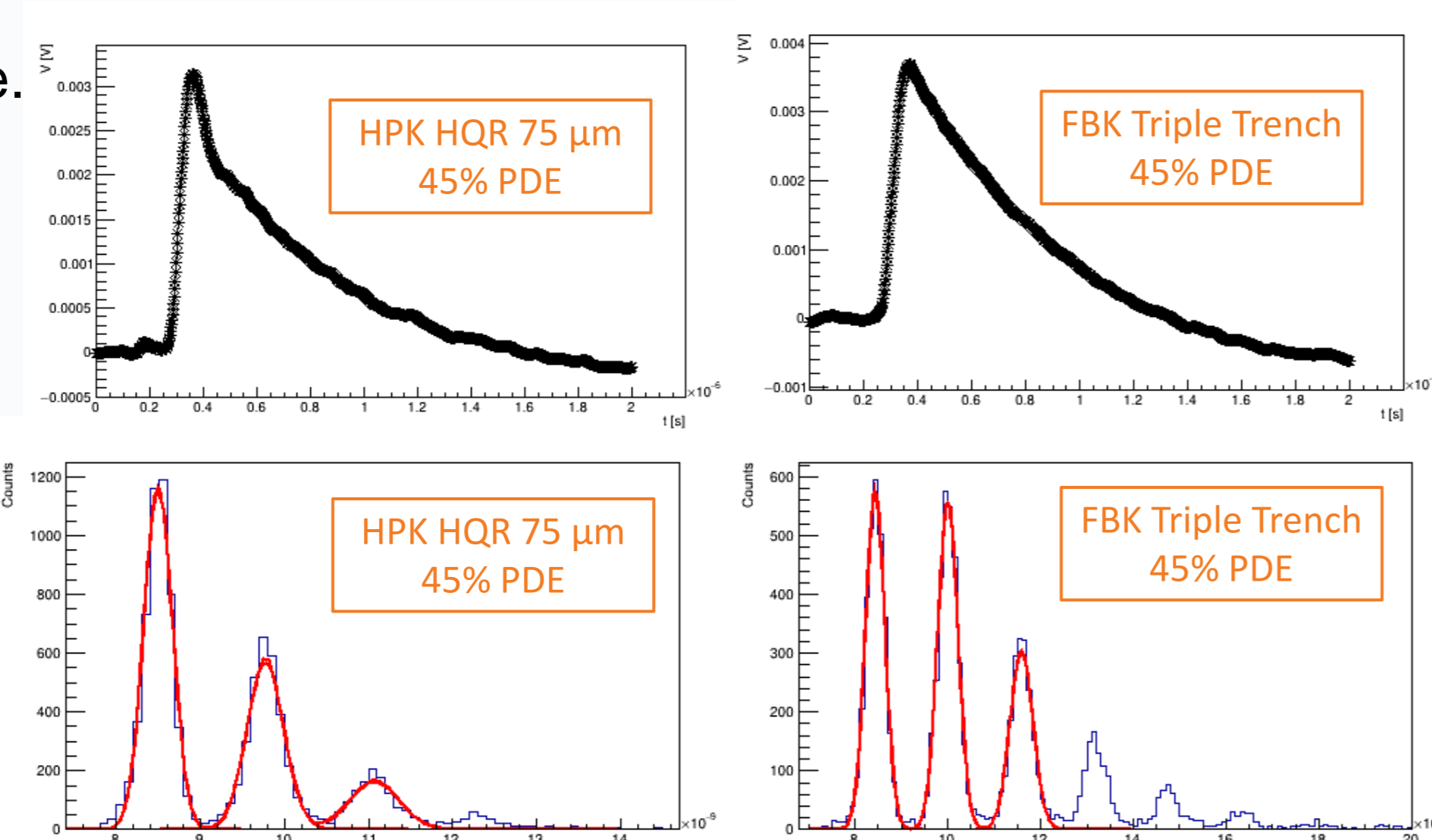
Cold Electronics : Active Ganging



- Used to collect the **signals of 48 SiPMs** of a supercell into a **single readout channel**.
- Each channel reads out **48 6x6 mm² SiPMs** → 60 nF total input capacitance.
- 1 channel per SuperCell, 4 channels per module, **6000 channels in DUNE** (1st module).
- **Two-stage amplifier** - SiGe bipolar transistor + fully differential op-amp.
- **Low series noise** is required → SiGe input transistor gives **0.37 nV/√Hz** at cryo temperature.
- **Low power consumption** (2 mW/channel) to prevent boiling of LAr.



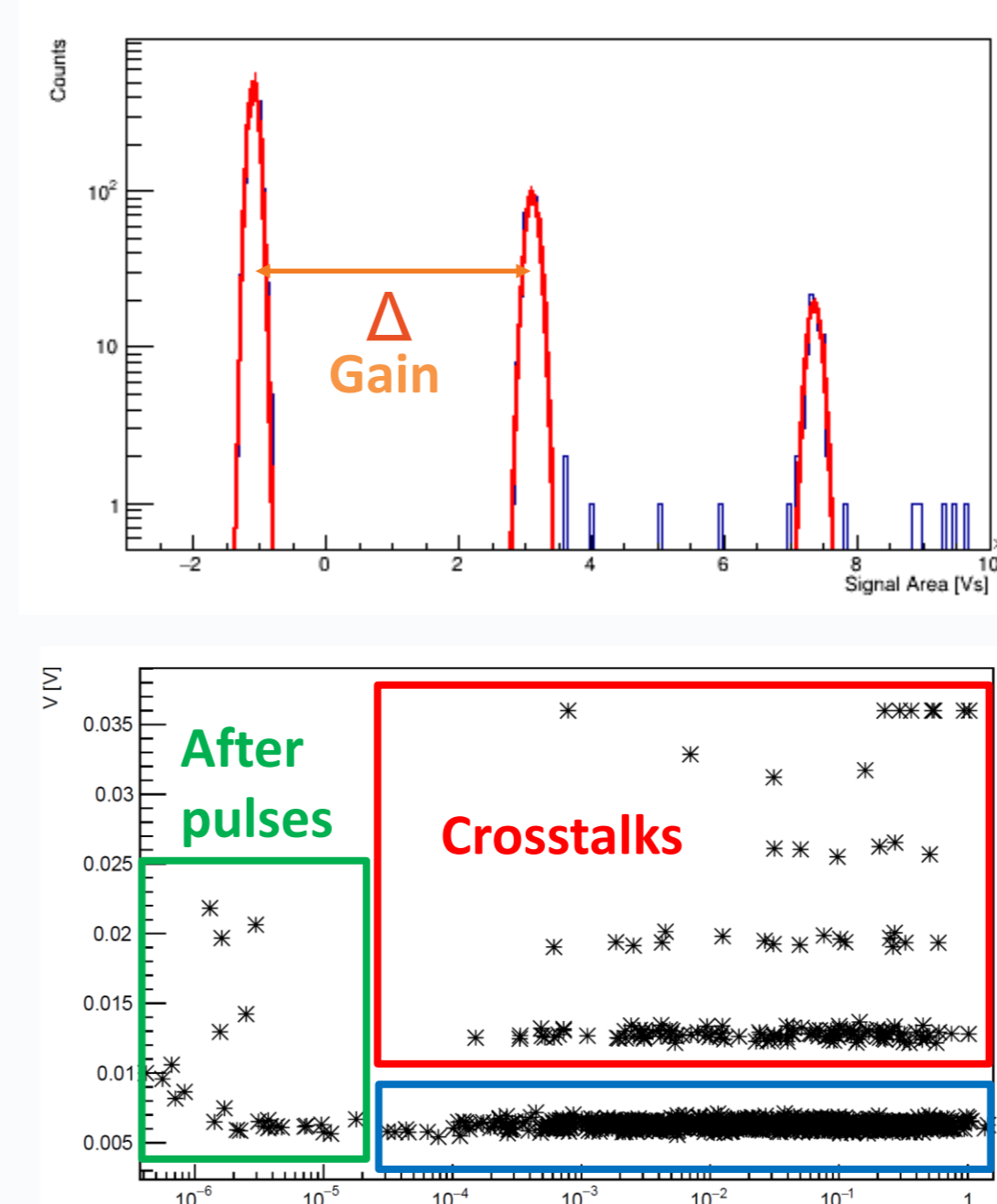
- Tested with **all candidate SiPMs for DUNE**.
- **Fast response**: <100 ns rise time.
- **Dynamic range** 2000 p.e.
- **Good S/N** ≈ 5-10 depending on SiPM type and overvoltage → Allows clear separation of photoelectron peaks (with 48 SiPMs in parallel).
- At 45% PDE:
 - ✓ **HPK HQR 75 μm**: 5.96 ;
 - ✓ **FBK Triple Trech**: 7.16.
- Next → Integration of all the cold parts (SiPM+routing+cold amp+cable).



- **48 SiPMs per Supercell**
 - ✓ 6 SiPMs per PMB passively ganged
 - ✓ 8 PMB actively ganged

- **192 SiPMs per PD module**
 - ✓ 4 electronics readout channels
 - ✓ 288,000 SiPMs in total

- **Two photosensor vendors** are being investigated: Hamamatsu (HPK) and FBK
 - ✓ 6 types (splits) of 6x6 mm² SiPMs developed specifically for DUNE: 4 from HPK (S13360 – LQR/HQR – 50/75 μm pitch) and 2 from FBK (NUV HD LF single/triple trench)



Final selection procedure

- **250 SiPMs per type** in the DUNE SiPM board tested at single SiPM level:
 - ✓ **IV measurements** for all SiPMs at room T and 77K;
 - ✓ 20 thermal cycles with controlled cooling down and warming up;
 - ✓ IV measurements repeated for all SiPMs and **complete characterization** for 5% sample per split.

- Test with **48 SiPM in active ganging** at different OV per each split: test of S/N and signal shape.

- **HPK HQR 75 μm** and **FBK Triple Trench** down selected.

ProtoDUNE run II production

- 3000(+1000) SiPMs FBK and 3000(+1000) SiPMs Hamamatsu.

- **Dedicated test stand** for automatized IV curve and DCR measurements.



Low level specs	Value
Max nominal operating V	[50 V at cold]
Dark count rate (DCR)	<100 mHz/mm ²
Correlated noise	<35%
Time resolution	<1 ms
Thermal cycles	>20
Recovery time	t ~ a few ms
PDE at 87 K	>35% at nominal OV
High level specs	Value
Dynamic range	1-2000 p.e.
S/N>4	Per supercell (48 SiPMs)
Trigger	1.5 p.e.

First selection procedure

- 25 SiPMs of each type **fully characterized** at single SiPM level:
 - ✓ **IV curve** measurements at room T at 77 K;
 - ✓ **gain, S/N** and **DCR** measured (77K) at OV to obtain 40%-45%-50% of PDE;
 - ✓ **20 thermal cycles** with controlled cooling down and warming up;
 - ✓ all measurements repeated after the thermal stresses.

- All splits **fulfill DUNE specifications**.

HPK HQR 75 μm

PDE	Gain (10 ⁶)	DCR (mHz/mm ²)	Cross-talk	After pulse
40	3.73	57.54	6.62	0.86
45	4.59	64.97	8.97	1.10
50	5.44	66.32	10.96	1.30

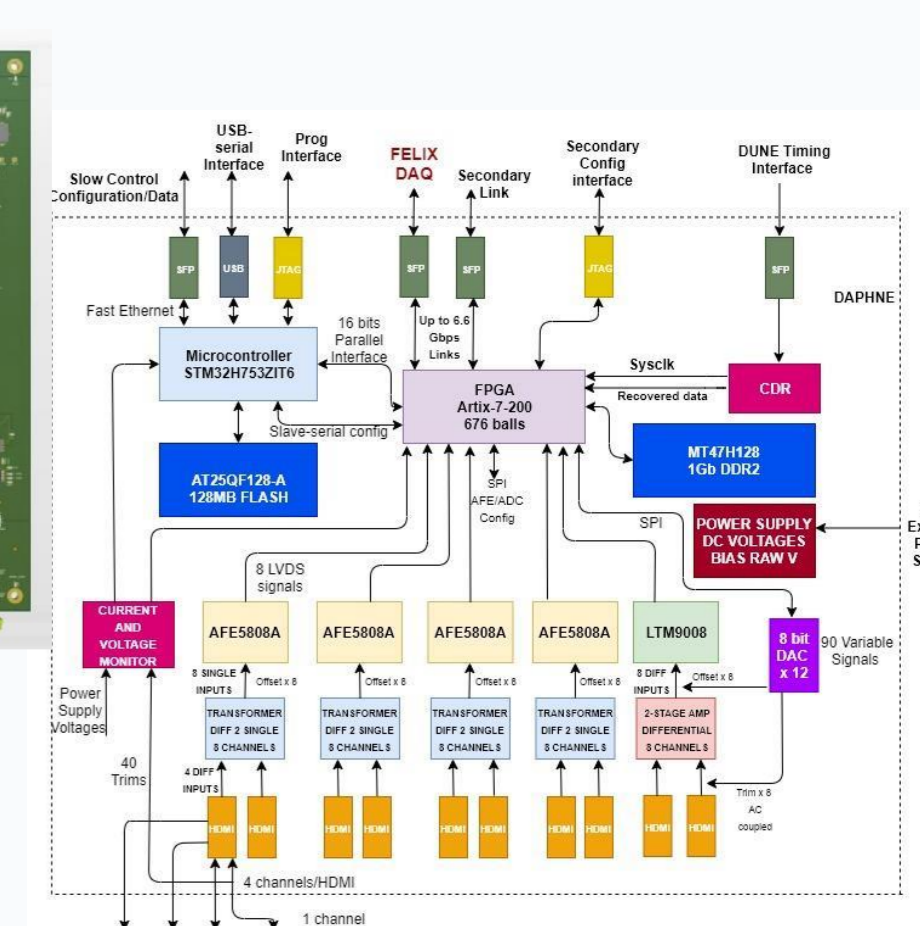
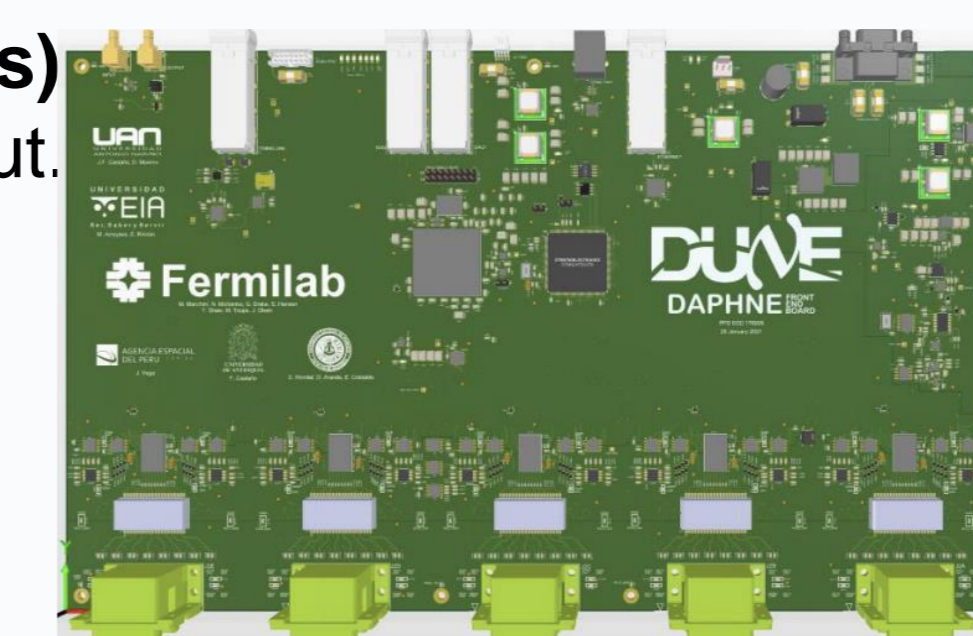
FBK Triple Trench

PDE	Gain (10 ⁶)	DCR (mHz/mm ²)	Cross-talk	After pulse
40	4.73	80.79	13.76	2.85
45	6.01	86.33	15.67	3.25
50	8.21	93.35	40.50	4.05

Warm Electronics : DAPHNE ASICs

- **DAPHNE (Detector electronics for Acquiring PHotons from NEutrinos)** design developed by the Mu2e redout.

- DAPHNE read-out boards:
 - ✓ **40 channels** per module;
 - ✓ **Artix 7 FPGA**;
 - ✓ **14 bit ultrasound ADC**;
 - ✓ Bias-Trim Voltage supply
 - ✓ Cold Electronics power supply +3V
 - ✓ Gigabit link up to **6.6 Gb/s** to **FELIXDAQ/full-mode** protocol
 - ✓ **DUNE Timing interface**



DAPHNE Scheme